# **NL27WZ08**

# **Dual 2-Input AND Gate**

The NL27WZ08 is a high performance dual 2-input AND Gate operating from a 1.65 V to 5.5 V supply.

### Features

- Extremely High Speed:  $t_{PD}$  2.5 ns (typical) at  $V_{CC}$  = 5 V
- Designed for 1.65 V to 5.5 V V<sub>CC</sub> Operation
- Over Voltage Tolerant Inputs
- LVTTL Compatible Interface Capability With 5 V TTL Logic with  $V_{CC} = 3 V$
- LVCMOS Compatible
- 24 mA Balanced Output Sink and Source Capability
- Near Zero Static Supply Current Substantially Reduces System Power Requirements
- Replacement for NC7WZ08
- Chip Complexity: FET = 124
- These Devices are Pb-Free and are RoHS Compliant
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

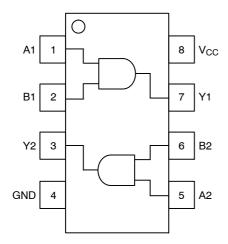
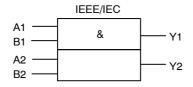


Figure 1. Pinout

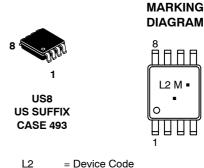






# **ON Semiconductor®**

http://onsemi.com



= Device Code М = Date Code\*

= Pb-Free Package

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(Note: Microdot may be in either location)

\*Date Code orientation may vary depending upon manufacturing location.

PIN ASSIGNMENT				
Pin	Function			
1	A1			
2	B1			
3	Y2			
4	GND			
5	A2			
6	B2			
7	Y1			
8	V <sub>CC</sub>			

## **FUNCTION TABLE** $Y = \overline{AB}$

Inp	Output				
А	В	Y			
L	L	L			
L	Н	L			
Н	L	L			
Н	Н	н			
H = HIGH Logic Level					

L = LOW Logic Level

#### **ORDERING INFORMATION**

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

#### **MAXIMUM RATINGS**

Symbol	Parameter	Value	Units	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	V	
VI	DC Input Voltage	-0.5 to +7.0	V	
Vo	DC Output Voltage	–0.5 to V <sub>CC</sub> + 0.5	V	
Ι <sub>ΙΚ</sub>	DC Input Diode Current V <sub>I</sub> < GND	-50	mA	
I <sub>OK</sub>	DC Output Diode Current $V_{O} < GND$	-50	mA	
Ι <sub>Ο</sub>	DC Output Sink Current	±50	mA	
I <sub>CC</sub>	DC Supply Current per Supply Pin	±100	mA	
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	-65 to +150	°C	
ΤL	Lead Temperature, 1 mm from Case for 10 Seconds	260	°C	
TJ	Junction Temperature under Bias	+150	°C	
$\theta_{JA}$	Thermal Resistance (Note 1)	250	°C/W	
PD	Power Dissipation in Still Air at 85°C	250	mW	
MSL	Moisture Sensitivity	Level 1		
F <sub>R</sub>	Flammability Rating Oxygen Index: 28 to 34	UL 94 V-0 @ 0.125 in		
V <sub>ESD</sub>	ESD Withstand Voltage Human Body Model (Note 2) Machine Model (Note 3) Charged Device Model (Note 4)	> 2000 > 200 N/A	V	
I <sub>Latch-Up</sub>	Latch-Up Performance Above V <sub>CC</sub> and Below GND at 85°C (Note 5)	±500	mA	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability. 1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

2. Tested to EIA/JESD22-A114-A.

3. Tested to EIA/JESD22-A115-A.

4. Tested to JESD22-C101-A.

5. Tested to EIA/JESD78.

#### **RECOMMENDED OPERATING CONDITIONS**

Symbol	Parameter		Max	Units
V <sub>CC</sub>	Supply Voltage Operating Data Retention Only	1.65 1.5	5.5 5.5	V
VI	Input Voltage (Note 6)	0	5.5	V
Vo	Output Voltage (HIGH or LOW State)		5.5	V
T <sub>A</sub>	Operating Free-Air Temperature	-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate $V_{CC} = 2.5 V \pm 0.2 V$ $V_{CC} = 3.0 V \pm 0.3 V$ $V_{CC} = 5.0 V \pm 0.5 V$		20 10 5	ns/V

6. Unused inputs may not be left open. All inputs must be tied to a high- or low-logic input voltage level.

## DC ELECTRICAL CHARACTERISTICS

			$V_{CC}$ $T_A = 25^{\circ}C$		$T_A = 25^{\circ}C$			C	–55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units		
V <sub>IH</sub>	High-Level Input Voltage		1.65 2.3 to 5.5	0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>			0.75 V <sub>CC</sub> 0.7 V <sub>CC</sub>		V		
V <sub>IL</sub>	Low-Level Input Voltage		1.65 2.3 to 5.5			0.25 V <sub>CC</sub> 0.3 V <sub>CC</sub>		0.25 0.3 V <sub>CC</sub>	V		
V <sub>OH</sub>	High-Level Output Voltage V <sub>IN</sub> = V <sub>IL</sub> or V <sub>IH</sub>	$\begin{split} I_{OH} &= 100 \ \mu A \\ I_{OH} &= -3 \ mA \\ I_{OH} &= -8 \ mA \\ I_{OH} &= -12 \ mA \\ I_{OH} &= -16 \ mA \\ I_{OH} &= -24 \ mA \\ I_{OH} &= -32 \ mA \end{split}$	1.65 to 5.5 165 2.3 2.7 3.0 3.0 4.5	$\begin{array}{c} V_{CC} - 0.1 \\ 1.29 \\ 1.9 \\ 2.2 \\ 2.4 \\ 2.3 \\ 3.8 \end{array}$	V <sub>CC</sub> 1.5 2.1 2.4 2.7 2.5 4.0		V <sub>CC</sub> - 0.1 1.5 1.9 2.2 2.4 2.3 3.8		V		
V <sub>OL</sub>	Low-Level Output Voltage $V_{IN} = V_{IH}$ or $V_{OH}$	$\begin{split} I_{OL} &= 100 \; \mu A \\ I_{OL} &= 3 \; m A \\ I_{OL} &= 8 \; m A \\ I_{OL} &= 12 \; m A \\ I_{OL} &= 16 \; m A \\ I_{OL} &= 24 \; m A \\ I_{OL} &= 32 \; m A \end{split}$	1.65 to 5.5 2.3 2.7 3.0 3.0 4.5		0.08 0.20 0.22 0.28 0.38 0.42	0.1 0.24 0.3 0.4 0.4 0.55 0.55		0.1 0.24 0.3 0.4 0.4 0.55 0.55	V		
I <sub>IN</sub>	Input Leakage Current	V <sub>IN</sub> = 5.5 V or GND	0 to 5.5			±0.1		±1.0	μΑ		
Icc	Quiescent Supply Current	V <sub>IN</sub> = 5.5 V or GND	5.5			1.0		10	μΑ		
I <sub>OFF</sub>	Power Off Leakage Current	V <sub>IN</sub> = 5.5 V or V <sub>OUT</sub> = 5.5 V	0			1.0		10	μΑ		

### AC ELECTRICAL CHARACTERISTICS $t_{R}$ = $t_{F}$ = 3.0 ns

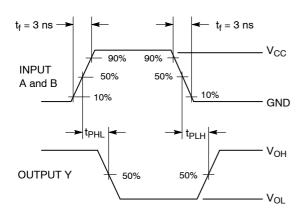
			V <sub>CC</sub>	•	T <sub>A</sub> = 25°C	;	–55°C ≤ T	<sub>A</sub> ≤ 125°C	
Symbol	Parameter	Condition	(V)	Min	Тур	Max	Min	Max	Units
t <sub>PLH</sub>	Propagation Delay	$R_L$ = 1 M $\Omega$ , $C_L$ = 15 pF	$1.8\pm0.15$	2.0	5.7	10.5	2.0	11.0	ns
t <sub>PHL</sub>	(Figure 3 and 4)		$2.5\pm0.2$	1.0	3.5	5.8	2.0	6.2	
		$\begin{array}{l} R_{L} = 1 \; M\Omega,  C_{L} = 15 \; pF \\ R_{L} = 500 \; \Omega,  C_{L} = 50 \; pF \end{array}$	$\textbf{3.3}\pm\textbf{0.3}$	0.8 1.2	2.6 3.2	3.9 4.8	0.8 1.2	4.3 5.2	
		$\begin{array}{l} R_{L} = 1 \; M\Omega,  C_{L} = 15 \; pF \\ R_{L} = 500 \; \Omega,  C_{L} = 50 \; pF \end{array}$	$5.0\pm0.5$	0.5 0.8	1.9 2.5	3.1 3.7	0.5 0.8	3.3 4.0	

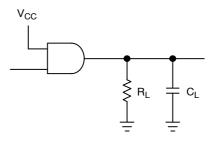
#### **CAPACITIVE CHARACTERISTICS**

Symbol	Parameter	Condition	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC}$ = 5.5 V, $V_{I}$ = 0 V or $V_{CC}$	4	pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 7)	10 MHz, V <sub>CC</sub> = 3.3 V, V <sub>I</sub> = 0 V or V <sub>CC</sub> 10 MHz, V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = 0 V or V <sub>CC</sub>	25 30	pF

7.  $C_{PD}$  is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation:  $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC}$ .  $C_{PD}$  is used to determine the no–load dynamic power consumption;  $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$ .

## **NL27WZ08**





A 1–MHz square input wave is recommended for propagation delay tests.

Figure 3. Switching Waveform



### **DEVICE ORDERING INFORMATION**

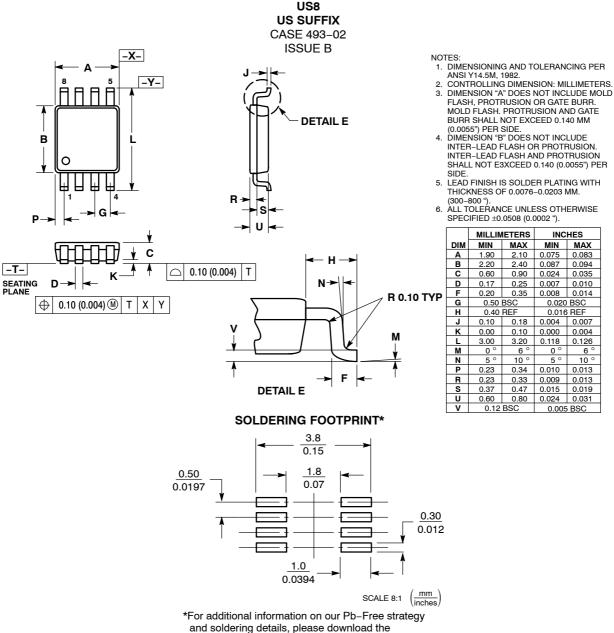
Device Order Number	Package Type	Shipping <sup>†</sup>
NL27WZ08USG	US8 (Pb-Free)	3000 / Tape & Reel
NLV27WZ08USG*	US8 (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

\*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable.

#### **NL27WZ08**

#### PACKAGE DIMENSIONS



ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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